Performance Characteristics:

- Frequency band: 33~37GHz
- Insertion loss: 1.1dB
- Isolation: 20dB
- Input/output voltage standing wave ratio: 1.37/1.2
- Chip size: 2mm x 1.1mm x 0.1mm

Product description:

CW-PD43040 is a GaAs MMIC0° four-way power splitter chip. The power splitter chip has the characteristics o f small plug loss, high isolation, small size, easy integration and so on. It is widely used in power distribution an d synthesis.

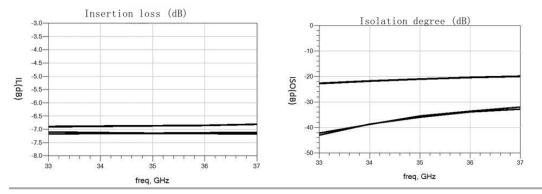
Electrical parameters: (T_A=25°C)

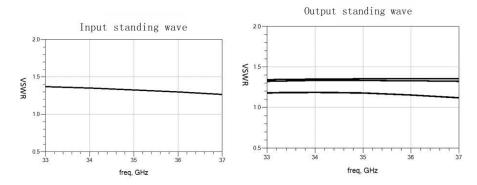
Indicators	Minimum	Typical value	Maximum value	Units
Frequency range	33~37			GHz
Insertion loss	-	1.1	-	dB
isolation	-	20	-	dB
Input voltage standing wave ratio	-	1.37	-	-
Output voltage standing wave ratio	-	1.2	-	-

Use limiting parameters:

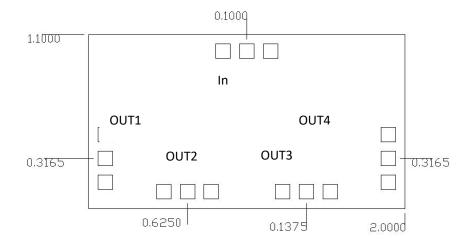
Input power	+27dBm
Storage temperature	-65°C~150°C
Service temperature	-55℃~85℃

Typical curve:

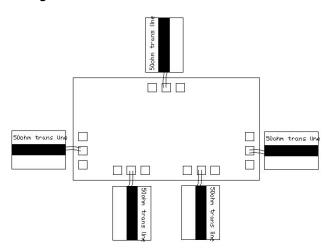








Suggested assembly drawing:



Instructions:

Storage: The chip must be placed in a container with electrostatic protection and stored in a nitrogen environment. **Cleaning treatment:** The bare chip must be operated and used in a purified environment. It is forbidden to use liquid cleaning agent to clean the chip.

Electrostatic protection: Strictly comply with the ESD protection requirements to avoid electrostatic damage to the components.

General operation: Use vacuum chuck or precision pointed tweezers to pick up the chip. Avoid touching the surface of the chip with tools or fingers during handling.

Mounting operation: The chip can be installed using AuSn solder eutectic welding or conductive adhesive bonding process. The mounting surface must be clean and flat.

Bonding operation: Input and output with 2 (recommended diameter of 25um gold wire) bonding wire, bonding wire length less than 250um is optimal. It is recommended to use the smallest possible ultrasonic energy. Bonding starts at the pressure point on the chip and ends at the package (or substrate)